

Sylvania Type ILE3

RESISTANCE COUPLED AMPLIFIER DATA

Fixed Bias Operation

	Ebb = 45 VOLTS						Ebb = 67.5 VOLTS						Ebb = 90 VOLTS						Ebb = 45 VOLTS					
	Rb		0.047		0.10		0.27		Rb		0.047		0.10		0.27		Rb		0.047		0.10		0.27	
Rcf	0.10	0.27	0.10	0.47	0.27	0.47	0.10	0.27	0.10	0.47	0.27	0.47	0.10	0.27	0.10	0.47	0.10	0.27	0.10	0.47	0.27	0.47	0.10	0.27
Ib	0.30	0.282	0.20	0.174	0.086	0.082	0.50	0.46	0.31	0.273	0.14	0.132	0.70	0.64	0.45	0.38	0.199	0.187	0.70	0.64	0.45	0.38	0.199	0.187
Ec	-0.7	-0.8	-0.6	-0.8	-0.7	-0.8	-1.2	-1.4	-1.1	-1.4	-1.0	-1.2	-1.8	-2.1	-1.5	-2.0	-1.5	-1.7	-1.8	-2.1	-1.5	-2.0	-1.5	-1.7
Eb	30.9	32.3	25.0	27.6	21.8	22.9	44	45.9	36.5	40.2	34.7	31.9	57.1	60.0	45.0	52.0	36.2	39.5	57.1	60.0	45.0	52.0	36.2	39.5
Esig	0.10	0.10	0.10	0.10	0.10	0.10	0.5	0.5	0.5	0.5	0.5	0.5	0.5	0.5	0.5	0.5	0.5	0.5	0.5	0.5	0.5	0.5	0.5	0.5
Eout	0.68	0.74	0.74	0.86	0.83	0.92	3.7	3.95	4.05	4.6	4.7	5.05	3.94	4.2	4.32	4.76	5.0	5.2	3.94	4.2	4.32	4.76	5.0	5.2
Gain	6.8	7.4	7.4	8.6	8.3	9.2	7.45	7.9	8.1	9.2	9.4	10.1	7.9	8.4	8.65	9.5	10.0	10.4	7.9	8.4	8.65	9.5	10.0	10.4
% Distortion	0.7	0.7	0.5	0.9	0.8	0.9	2.5	2.1	2.9	2.3	3.3	3.1	1.7	1.4	1.7	1.3	2.4	2.2	1.7	1.4	1.7	1.3	2.4	2.2
Esig (1)	0.50	0.56	0.42	0.56	0.50	0.56	0.85	0.99	0.78	0.99	0.7	0.85	1.27	1.48	1.06	1.41	1.06	1.2	1.27	1.48	1.06	1.41	1.06	1.2
Eout	3.33	4.1	3.1	4.85	4.22	5.2	6.3	7.8	6.3	9.1	6.6	8.6	10.0	12.4	9.15	13.4	10.6	12.5	10.0	12.4	9.15	13.4	10.6	12.5
Gain	6.66	7.32	7.4	8.65	8.44	9.3	7.42	7.88	8.1	9.2	9.4	10.1	7.88	8.4	8.65	9.5	10.0	10.4	7.88	8.4	8.65	9.5	10.0	10.4
% Distortion	4.4	4.5	4.1	4.6	5.0	5.0	4.6	4.9	5.0	5.0	4.8	5.0	4.7	5.0	5.0	5.0	5.0	5.0	4.7	5.0	4.7	5.0	5.0	5.0

Note (1) Peak signal equal to bias. Optimum bias chosen for 5% maximum distortion. Grid return to pin No. 8.

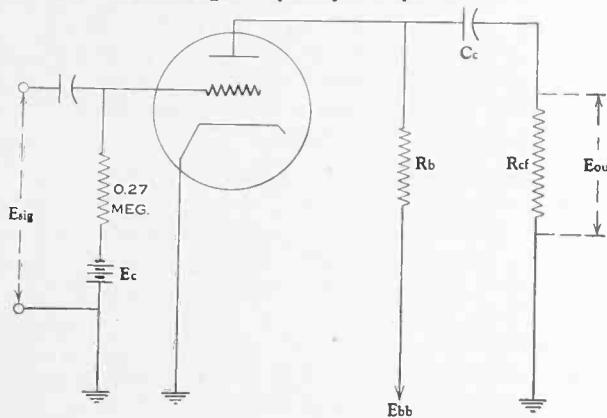
SYMBOLS USED

Symbol	Function	Unit	Symbol	Function	Unit
Rb	Plate Load Resistor	Megohms	Esig	Input Signal	R-M-S Volts
Rcf	Grid Resistor of following tube	Megohms	Eout	Output to following grid	R-M-S Volts
Ebb	Plate Supply Voltage	Volts	Ib	Plate Current	Ma.
Eb	Plate Voltage at plate	Volt	Cc	Coupling Condenser	mfd.
Ec	Grid to Neg. Filament Voltage	Volts			

Values of capacity are not specified since these are dependent mostly on the frequency characteristics required in each individual case.

$$\text{For low frequency limit } f_1 \quad C_c = \frac{1.6 \times 10^6}{f_1 R_{cf}} \quad \text{mfd.}$$

Some text books show a more complicated method for calculating by-pass condensers, but this method is quite rapid and gives conservative values. The loss due to incomplete by-passing will be less than 1%. The size condenser may be halved where economy is essential unless stages are cascaded and highest quality is required.



(Continued from page 11)

Nomenclature

Cathode ray tube type numbers consist of a number followed by two letters followed by another number. The first number gives the maximum bulb diameter to the nearest inch. The first letter is a serial letter identifying a particular design in that bulb size. The use of the same letter after different first numbers does not indicate any similarity of design. For example,

the type 3AP1 is a tube very little like 5AP1. The second letter is always "P", which, incidentally, identifies the type as a cathode ray tube. It stands for "phosphor" and with the final number, identifies the type of screen material used in the tube.

Screen Materials

Most types are available with any of several different screens, for example, 5CP1, 5CP4 and 5CP7

are all similar except for the screens used. Like the electrode assemblies, screens have varying characteristics which make each most suitable for a particular type of service. A discussion of screen materials is beyond the scope of this paper, but it should be noted that no particular material is the best for all uses. The manufacturer's data should be consulted for help in selecting the best screen for any particular application.

RESISTANCE COUPLED AMPLIFIER DATA

Zero Bias Operation

Sylvania Type 1LH4

	Ebb = 45 VOLTS (See Note 2)				Ebb = 67.5 VOLTS				Ebb = 90 VOLTS			
	0.27		0.47		1.0		0.27		0.47		1.0	
R _b	0.47	1.0	4.7	1.0	2.2	4.7	10.0	0.47	1.0	4.7	10.0	0.47
R _{cf}	0.0075	0.0075	0.0064	0.0064	0.005	0.005	0.03	0.03	0.03	0.03	0.03	0.03
I _b	43	43	42	42	40	40	59.4	59.4	56.1	56.1	50.7	50.7
E _b	.03	.03	.03	.03	.03	.03	0.05	0.05	0.05	0.05	0.05	0.05
E _{sig}	.168	.200	.234	.270	.336	.405	.465	.490	.77	.91	1.03	1.26
E _{out}	5.6	7.8	9.0	11.2	13.5	15.5	15.4	18.2	20.6	21.6	25.2	25.8
Gain	5.1	5.0	4.9	4.5	4.2	3.8	3.9	3.7	3.6	3.5	3.3	2.9
% Distortion	.03	.03	.03	.04	.04	.05	.05	.05	.07	.08	.08	.08
E _{sig (1)}	.168	.200	.234	.270	.445	.465	.67	.76	.81	.91	1.44	1.63
E _{out}	5.6	6.7	7.8	9.0	11.1	11.6	13.4	15.2	16.2	15.3	18.0	20.4
Gain	5.1	5.0	4.9	4.5	5.2	5.1	5.2	5.0	4.9	4.7	4.6	4.5
% Distortion												

Note (1) Maximum signal for 5.0% distortion. Note (2) Operation at Ebb = 45 volts is not recommended. Above 45 volt data is shown only to assist in determining end of life performance with 67.5 volt supply.
For 45 volt supply type 1LD5 is recommended.

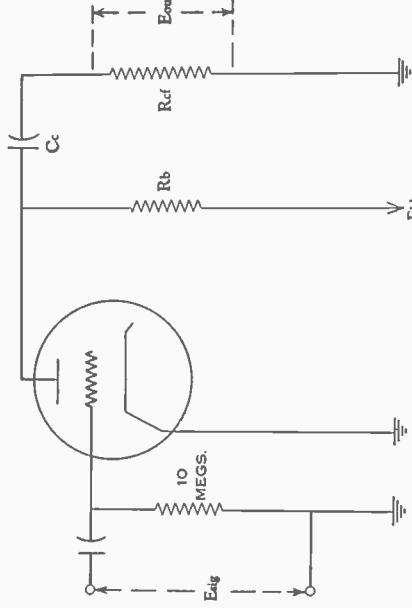
SYMBOLS USED

Symbol	Function	Unit	Symbol	Function	Unit
R _b	Plate Load Resistor	Megohms	E _{sig}	Input Signal	R-M-S Volts
R _{cf}	Grid Resistor of following tube	Megohms	E _{out}	Output to following grid	R-M-S Volts
E _b	Plate Supply Voltage	Volts	I _b	Plate Current	Ma.
E _b	Plate Voltage at plate	Volts	C _c	Coupling Condenser	mfd.

Values of capacity are not specified since these are dependent mostly on the frequency characteristics required in each individual case.

$$\text{For low frequency limit } f_1 \quad C_c = \frac{1.6 \times 10^6}{f_1 R_{cf}} \text{ mfd.}$$

Some text books show a more complicated method for calculating by-pass condensers, but this method is quite rapid and gives conservative values. The loss due to incomplete by-passing will be less than 1%. The size condenser may be halved where economy is essential unless stages are cascaded and highest quality is required.



Sylvania Type 1LH4

Sylvania Type 7A4
" Type 7N7

RESISTANCE COUPLED AMPLIFIER DATA

Self Bias Operation Type 7A4 or Single Section of Type 7N7

Rb	Ebb = 100 VOLTS						Ebb = 250 VOLTS					
	0.047		0.10		0.27		0.047		0.10		0.27	
	Rcf	Rk	Ib	Ec	Eb	Esig	Eout	Gain	% Distortion	Esig (1)	Eout	Gain
0.1	0.27	0.1	0.47	0.27	0.47	0.5	7.1	13.2	1.9	0.95	12.5	13.1
1800	2200	3300	4700	8200	10,000	1.0	6.6	14.2	1.8	1.13	15.5	13.9
1.05	0.97	0.57	0.50	0.24	0.22	2.79	7.4	14.8	1.4	1.8	15.0	13.6
-1.89	-2.13	-1.90	-2.35	-1.93	-2.19	-4.18	-5.28	-14.8	-1.4	-2.70	-3.50	-14.7
50.6	54.4	43.0	50.0	36.5	40.9	119	137	101	1.4	1.4	2.55	3.30
0.5	0.5	0.5	0.5	0.5	0.5	1.0	1.0	1.0	1.4	1.4	3.30	2.64
Eout	6.6	7.1	6.8	7.4	7.3	14.8	15.0	15.2	1.4	1.4	1.8	1.3
Gain	13.2	14.2	13.6	14.8	14.6	14.8	15.0	15.2	1.4	1.4	1.8	1.3
% Distortion	1.9	1.8	2.4	2.0	2.0	1.7	1.8	1.8	1.4	1.4	1.8	1.3
Esig (1)	0.95	1.13	0.95	1.3	0.95	1.20	2.70	3.50	2.70	3.50	2.55	3.30
Eout	12.5	15.5	12.9	19.2	13.7	17.7	39.9	52.5	39.9	52.5	38.4	53.0
Gain	13.1	13.9	13.6	14.7	14.4	14.7	14.7	15.0	14.7	15.0	15.0	16.1
% Distortion	3.9	4.2	4.9	4.7	4.4	4.5	4.1	4.9	4.1	4.9	4.9	4.6

Note (1) For self bias operation this is taken at the grid current point with less than $\frac{1}{2}$ microampere grid current.

SYMBOLS USED

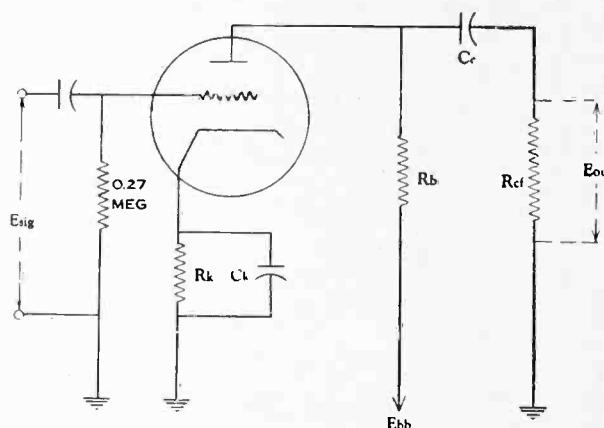
Symbol	Function	Unit	Symbol	Function	Unit
Rb	Plate Load Resistor	Megohms	Esig	Input Signal	R-M-S Volts
Rcf	Grid Resistor of following tube	Megohms	Eout	Output to following grid	R-M-S Volts
Rk	Cathode Bias Resistor	Ohms	Ib	Plate Current	Ma.
Ebb	Plate Supply Voltage	Volts	Ck	Cathode by-pass Condenser	mmf.
Eb	Plate Voltage at plate	Volts	Cc	Coupling Condenser	mmf.
Ec	Grid to Cathode Voltage	Volts			

Values of capacity are not specified since these are dependent mostly on the frequency characteristics required in each individual case.

$$\text{For low frequency limit} = f_1 \quad C_c = \frac{1.6 \times 10^6}{f_1 R_{cf}} \text{ mfd.}$$

$$C_k = \frac{1.6 \times 10^6}{f_1 R_k} \text{ mfd.}$$

Some text books show a more complicated method for calculating these by-pass condensers, but this method is quite rapid and gives conservative values. The loss due to incomplete by-passing will be less than 1% except for the cathode by-pass where it will be about 3%. The size condenser may be halved where economy is essential unless stages are cascaded and highest quality is required.



RESISTANCE COUPLED AMPLIFIER DATA

Sylvania Type 7B4

Self Bias Operation

Zero Bias Operation

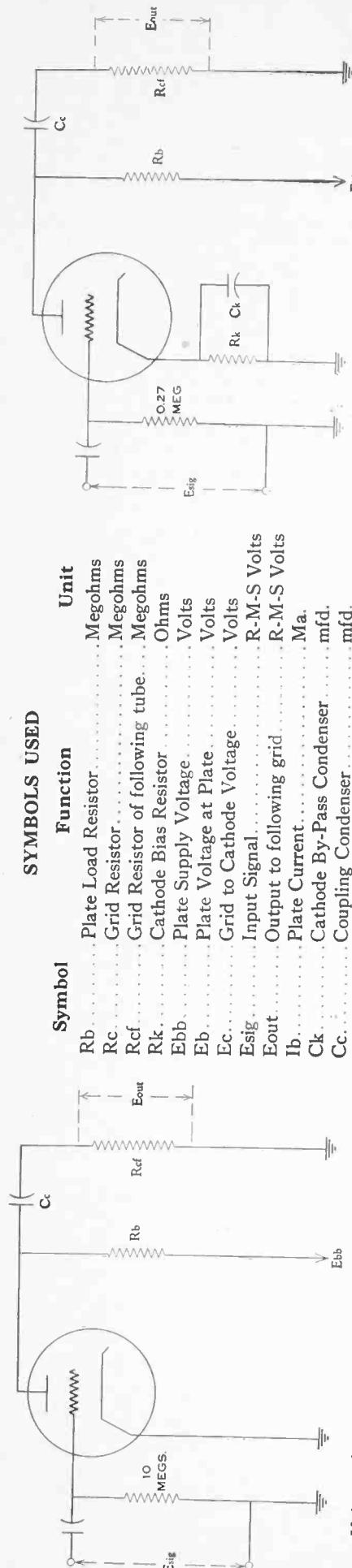
	Ebb = 100 VOLTS			Ebb = 250 VOLTS		
	0.1	0.27	0.47	0.1	0.27	0.47
Rb	0.27	0.47	1.0	0.27	0.47	1.0
Rcf
Rk	0.223	0.223	0.126	0.126	0.89	0.89
Ib
Ec
Eb	77.7	77.7	66.0	66.0	58.2	58.2
Esig	0.1	0.1	0.1	0.1	0.1	0.1
Eout	3.85	4.15	4.32	4.9	5.45	5.0
Gain	38.5	41.5	43.2	49.0	54.5	50.0
% Dist.	4.6	4.3	5.0	4.2	3.3	4.5
Esig (1)	0.1	0.1	0.1	0.11	0.14	0.1
Eout	3.85	4.55	4.32	5.35	7.4	5.0
Gain	38.5	41.4	43.2	48.6	53.0	50.0
% Dist.	4.6	4.9	5.0	4.7	5.0	4.5

Note (1) Maximum signal for 5% Distortion.

	Ebb = 100 VOLTS			Ebb = 250 VOLTS		
	0.1	0.27	0.47	0.1	0.27	0.47
Rb	0.27	0.47	1.0	0.27	0.47	1.0
Rcf
Rk	0.223	0.223	0.126	0.126	0.89	0.89
Ib
Ec
Eb	77.7	77.7	66.0	66.0	58.2	58.2
Esig	0.1	0.1	0.1	0.1	0.1	0.1
Eout	3.85	4.15	4.32	4.9	5.45	5.0
Gain	38.5	41.5	43.2	49.0	54.5	50.0
% Dist.	4.6	4.3	5.0	4.2	3.3	4.5
Esig (1)	0.1	0.1	0.1	0.11	0.14	0.1
Eout	3.85	4.55	4.32	5.35	7.4	5.0
Gain	38.5	41.4	43.2	48.6	53.0	50.0
% Dist.	4.6	4.9	5.0	4.7	5.0	4.5

Note (1) For self bias operation this is taken at the grid current point with less than $\frac{1}{6}$ microampere grid current.

SYMBOLS USED



Symbol	Function	Unit
Rb	Plate Load Resistor	Megohms
Rc	Grid Resistor	Megohms
Rcf	Grid Resistor of following tube	Megohms
Rk	Cathode Bias Resistor	Ohms
Ebb	Plate Supply Voltage	Volts
Eb	Plate Voltage at Plate	Volts
Ec	Grid to Cathode Voltage	Volts
Esig	Input Signal	R-M-S Volts
Eout	Output to following grid	R-M-S Volts
Ib	Plate Current	M.A.
Ck	Cathode By-Pass Condenser	mfd.
Cc	Coupling Condenser	mfd.

Values of capacity are not specified since these are dependent mostly on the frequency characteristics required in each individual case.

$$\text{For low frequency limit } = f_1 \quad C_k = \frac{1.6 \times 10^6}{f_1 R_k} \quad \text{mfd.}$$

$$C_c = \frac{1.6 \times 10^6}{f_1 R_{cf}} \quad \text{mfd.}$$

Some text books show a more complicated method for calculating these by-pass condensers, but this method is quite rapid and gives conservative values. The loss due to incomplete by-passing will be less than 1% except for the cathode by-pass where it will be about 3%. The size condenser may be halved where economy is essential unless stages are cascaded and highest quality is required.

RESISTANCE COUPLED AMPLIFIER DATA

Zero Bias Operation

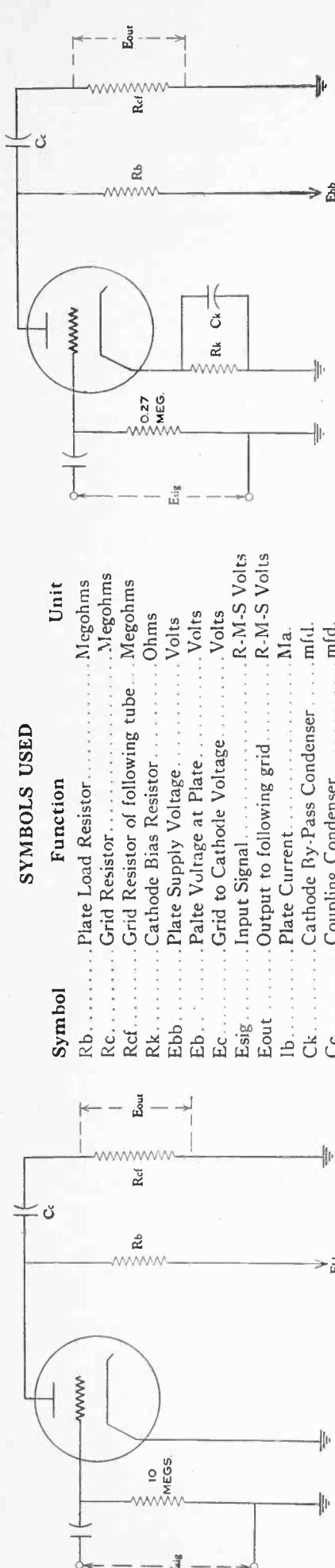
Ebb = 100 VOLTS			
Rb	0.1	0.27	0.47
Rcf	0.27	0.47	1.0
Rk
Ib	0.228	0.228	0.132
Ec
Eb	77.2	64.4	64.4
Esig	0.1	0.1	0.1
Eout	3.3	3.55	3.95
Gain	33.0	35.5	39.5
% Dist.	3.0	2.9	3.8
Esig (1)	0.15	0.16	0.12
Eout	4.73	5.4	6.12
Gain	31.5	33.8	38.7
% Dist.	4.9	5.0	4.8

Note (1) Maximum Signal for 5.0% Distortion

Ebb = 250 VOLTS			
Rb	0.1	0.27	0.47
Rcf	0.27	0.47	1.0
Rk
Ib	0.214	0.214	0.138
Ec	-0.835	-0.835	-0.774
Eb	78.6	78.6	62.8
Esig	0.1	0.1	0.1
Eout	3.3	3.5	4.1
Gain	33.0	35.0	41.0
% Dist.	2.7	2.6	3.2
Esig (1)	0.16	0.16	0.10
Eout	5.15	5.5	4.1
Gain	32.2	34.4	41.0
% Dist.	4.5	4.0	3.2

Note (1) For self bias operation this is taken at the grid current point with less than $\frac{1}{8}$ Microampere grid current.

SYMBOLS USED



Values of capacity are not specified since these are dependent mostly on the frequency characteristics required in each individual case.

For low frequency limit = f_1 $C_k = \frac{1.6 \times 10^6}{f_1 R_k}$ mfd.

$$C_c = \frac{1.6 \times 10^6}{f_1 R_{cf}} \text{ mfd.}$$

Self Bias Operation

Ebb = 100 VOLTS			
Rb	0.1	0.27	0.47
Rcf	0.27	0.47	1.0
Rk
Ib	0.228	0.228	0.132
Ec
Eb	77.2	64.4	64.4
Esig	0.1	0.1	0.1
Eout	3.3	3.55	3.95
Gain	33.0	35.5	39.5
% Dist.	3.0	2.9	3.8
Esig (1)	0.15	0.16	0.12
Eout	4.73	5.4	6.12
Gain	31.5	33.8	38.7
% Dist.	4.9	5.0	4.8

Note (1) For self bias operation this is taken at the grid current point with less than $\frac{1}{8}$ Microampere grid current.

Sylvania Type 7B6

Some text books show a more complicated method for calculating these by-pass condensers, but this method is quite rapid and gives conservative values. The loss due to incomplete by-passing will be less than 1% except for the cathode by-pass where it will be about 3%. The size condenser may be halved where economy is essential unless stages are cascaded and highest quality is required.

Sylvania Type 7C7

RESISTANCE COUPLED AMPLIFIER DATA

Self Bias Operation

	Ebb = 100 VOLTS						Ebb = 250 VOLTS					
Rb	0.1		0.27		0.47		0.1		0.27		0.47	
Rc ₂	0.47		1.2		1.8		0.47		1.2		2.2	
Rcf	0.27	0.47	0.27	0.47	1.0	0.47	1.0	0.27	0.47	0.27	0.47	1.0
Rk	1000	1000	2200	2200	2200	3900	3900	470	470	1000	1000	1500
Ib	0.62	0.62	0.27	0.27	0.27	0.168	0.168	1.76	1.76	0.75	0.75	0.44
Ic ₂	0.145	0.145	0.064	0.064	0.064	0.465	0.465	0.41	0.41	0.177	0.177	0.10
E _{c1}	-0.765	-0.765	-0.735	-0.735	-0.735	-0.622	-0.622	-1.02	-1.02	-0.927	-0.927	-0.81
E _{c2}	31.9	31.9	23.3	23.3	23.3	16.3	16.3	57.2	57.2	37.5	37.5	30
E _b	38	38	27.2	27.2	27.2	21	21	74	74	47.5	47.5	43.5
E _{sig}	0.1	0.1	0.1	0.1	0.1	0.1	0.1	0.1	0.1	0.1	0.1	0.1
E _{out}	7.0	8.05	8.0	10.0	12.0	9.8	12.5	10.6	12.0	13.0	17.0	20.4
Gain	70.0	80.5	80	100	120	98	125	106	120	130	170	204
% Distortion	2.7	2.4	3.7	2.7	2.3	3.2	1.9	1.6	1.4	1.5	1.6	2.4
E _{sig} (%)	0.18	0.18	0.14	0.14	0.14	0.14	0.14	0.4	0.4	0.27	0.27	0.18
E _{out}	12.3	13.9	10.8	13.8	16.7	13.2	17.0	40.3	45.2	33.0	41.6	49.5
Gain	68.5	77.2	77.2	98.7	119	94.5	121.5	101	113	122	154	183.5
% Distortion	4.7	4.1	5.5	4.6	3.8	4.9	5.0	4.3	4.4	5.0	5.0	5.9

Note (1) For self bias operation this is taken at the grid current point with less than $\frac{1}{8}$ microampere grid current.

SYMBOLS USED

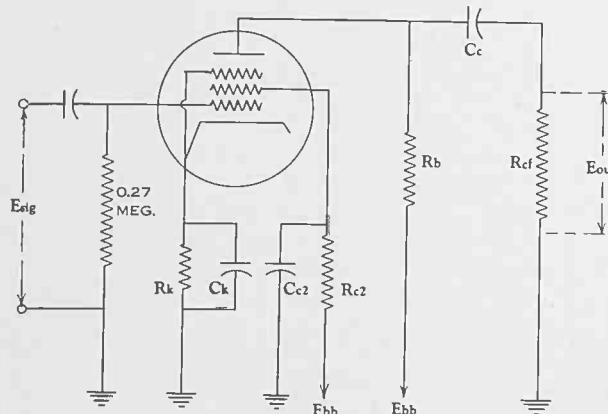
Symbol	Function	Unit	Symbol	Function	Unit
Rb	Plate Load Resistor	Megohms	E _{sig}	Input Signal	R-M-S Volts
Rcf	Grid Resistor of following tube	Megohms	E _{out}	Output to following grid	R-M-S Volts
Rk	Cathode Bias Resistor	Ohms	I _b	Plate Current	Ma.
E _{bb}	Plate Supply Voltage	Volts	C _k	Cathode by-pass Condenser	mmf.
E _b	Plate Voltage at plate	Volts	C _c	Coupling Condenser	mmf.
E _c	Grid to Cathode Voltage	Volts			

Values of capacity are not specified since these are dependent mostly on the frequency characteristics required in each individual case.

$$\text{For low frequency limit } = f_1 \quad C_c = \frac{1.6 \times 10^6}{f_1 R_{cf}} \text{ mfd.}$$

$$C_k = \frac{1.6 \times 10^6}{f_1 R_k} \text{ mfd.}$$

Some text books show a more complicated method for calculating these by-pass condensers, but this method is quite rapid and gives conservative values. The loss due to incomplete by-passing will be less than 1% except for the cathode by-pass where it will be about 3%. The size condenser may be halved where economy is essential unless stages are cascaded and highest quality is required.



SYLVANIA TYPE 7E6

RESISTANCE COUPLED AMPLIFIER DATA

Self Bias Operation

Rb	Ebb = 100 VOLTS						Ebb = 250 VOLTS					
	0.047	0.1	0.27	0.047	0.1	0.27	0.047	0.1	0.27	0.047	0.1	0.27
Rcf	0.1	0.27	0.1	0.47	0.27	0.47	0.1	0.27	0.1	0.47	0.27	0.47
Rk	1800	2200	2700	3900	6800	8200	1500	1800	2200	3300	5600	8200
Ib	1.07	1.0	0.62	0.56	0.256	0.240	2.85	2.69	1.63	1.46	0.661	0.60
Ec	-1.93	-2.2	-1.67	-2.18	-1.74	-1.97	-4.27	-4.84	-3.59	-4.82	-3.70	-4.92
Eb	49.6	53.0	38	44	31	35.2	116	123.8	87	104	71.8	88
Esig	0.5	0.5	0.5	0.5	0.5	0.5	1.0	1.0	1.0	1.0	1.0	1.0
Eout	5.3	5.4	5.6	5.8	5.7	5.8	11.2	11.8	11.8	12.4	12.1	12.2
Gain	10.6	10.8	11.2	11.6	11.4	11.6	11.2	11.8	11.8	12.4	12.1	12.2
% Distortion	2.1	1.9	2.0	1.8	2.2	1.8	1.3	1.2	1.8	1.3	1.8	1.3
Esig (1)	1.02	1.24	0.87	1.23	0.97	1.10	2.80	3.25	2.23	3.27	2.40	3.32
Eout	10.6	13.2	9.5	14.2	11.0	12.8	31.2	38.0	26.0	40.4	28.5	40.6
Gain	10.4	10.6	10.9	11.5	11.3	11.6	11.1	11.7	11.7	12.3	12.1	12.2
% Distortion	4.5	4.9	4.7	4.8	4.9	4.3	4.5	4.6	4.4	4.5	4.5	4.9

Note (1) For self bias operation this is taken at the grid current point with less than $\frac{1}{8}$ microampere grid current

SYMBOLS USED

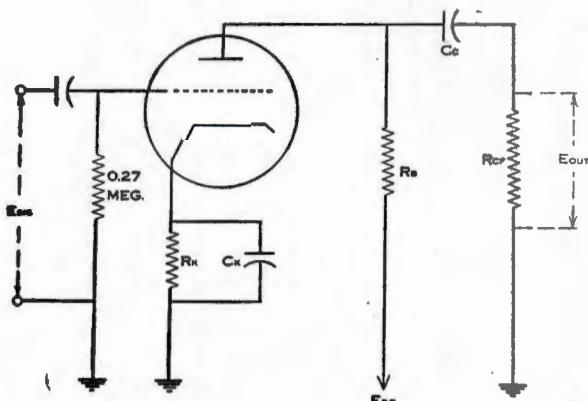
Symbol	Function	Unit	Symbol	Function	Unit
Rb	Plate Load Resistor	Megohms	Eisg	Input Signal	R-M-S Volts
Rcf	Grid Resistor of following tube	Megohms	Eout	Output to following grid	R-M-S Volts
Rk	Cathode Bias Resistor	Ohms	Ib	Plate Current	Ma.
Ebb	Plate Supply Voltage	Volts	Ck	Cathode by-pass Condenser	mmf.
Eb	Plate Voltage at plate	Volts	Cc	Coupling Condenser	mmf.
Ec	Grid to Cathode Voltage	Volts			

Values of capacity are not specified since these are dependent mostly on the frequency characteristics required in each individual case.

$$\text{For low frequency limit} = f_1 \quad C_c = \frac{1.6 \times 10^6}{f_1 \text{ Rcf}} \quad \text{mfd.}$$

$$C_L = \frac{1.6 \times 10^6}{f_1 \text{ Rk}} \quad \text{mfd.}$$

Some text books show a more complicated method for calculating these by-pass condensers, but this method is quite rapid and gives conservative values. The loss due to incomplete by-passing will be less than 1% except for the cathode by-pass where it will be about 3%. The size condenser may be halved where economy is essential unless stages are cascaded and highest quality is required.



Data like the above are now given in slightly rearranged form in the new manual. If enough servicemen wish us to continue printing these in the 8½" x 11" size for use in notebooks we will arrange to include one every other month or so. Otherwise we will consider that the data as given in the manual is equally convenient for you.

Sylvania Type 7R7

RESISTANCE COUPLED AMPLIFIER DATA

Self Bias Operation

	Ebb = 100 VOLTS						Ebb = 250 VOLTS					
	0.1		0.2		0.47		0.1		0.27		0.47	
Rc ₂	0.39		1.0		1.8		0.39		1.0		1.8	
Rcf	0.27	0.47	0.27	0.47	1.0	0.47	1.0	0.27	0.47	0.27	0.47	1.0
Rk	1200	1200	2700	2700	2700	4700	4700	470	470	1000	1000	1200
Ib	0.61	0.61	0.271	0.271	0.271	0.163	0.163	1.75	1.75	0.75	0.75	0.74
Ic ₂	0.173	0.173	0.076	0.076	0.076	0.044	0.044	0.49	0.49	0.212	0.212	0.207
Ec ₁	-0.94	-0.94	-0.938	-0.938	-0.938	-0.974	-0.974	-1.05	-1.05	-0.962	-0.962	-1.14
Ec ₂	32.5	32.5	23.5	23.5	23.5	20.5	20.5	59	59	38	38	43
Eb	39	39	26.9	26.9	26.9	23.4	23.4	75	75	47.5	47.5	50
Esig	0.1	0.1	0.1	0.1	0.1	0.1	0.1	0.1	0.1	0.1	0.1	0.1
Eout	7.8	8.9	8.0	10.2	12.2	9.6	12.5	13.6	15.5	15.4	19.8	22.0
Gain	78	89	80	102	122	96	125	136	155	154	198	220
% Distortion	4.6	4.3	5.0	3.8	3.0	5.2	3.9	2.2	2.1	2.8	2.1	2.0
Esig (1)	0.11	0.11	0.1	0.1	0.1	0.1	0.1	0.22	0.22	0.15	0.15	0.2
Eout	8.55	9.8	8.0	10.2	12.2	9.6	12.5	29	33	22.5	28.0	41.5
Gain	77.8	89	80	102	122	96	129	132	150	150	187	207.5
% Distortion	5.1	4.6	5.0	3.8	3.0	5.2	3.9	4.8	4.3	4.5	3.8	5.0

Note (1). For self bias operation this is taken at the grid current point with less than $\frac{1}{2}$ microampere grid current.

SYMBOLS USED

Symbol	Function	Unit	Symbol	Function	Unit
Rb	Plate Load Resistor	Megohms	Esig	Input Signal	R-M-S Volts
Rcf	Grid Resistor of following tube	Megohms	Eout	Output to following grid	R-M-S Volts
Rk	Cathode Bias Resistor	Ohms	Ib	Plate Current	Ma.
Ebb	Plate Supply Voltage	Volts	Ic ₂	Screen Grid Current	Ma.
Eb	Plate Voltage at plate	Volts	Ck	Cathode by-pass Condenser	mmf.
Ec ₁	Grid to Cathode Voltage	Volts	Cc	Coupling Condenser	mmf.
Ec ₂	Screen Grid Voltage at screen	Volts	Cc ₂	Screen by-pass Condenser	mfd.

Values of capacity are not specified since these are dependent mostly on the frequency characteristics required in each individual case.

$$\text{For low frequency limit } = f_1 \quad Cc = \frac{1.6 \times 10^6}{f_1 Rcf} \text{ mfd.}$$

$$Ck = \frac{1.6 \times 10^6}{f_1 Rk} \text{ mfd.}$$

Some text books show a more complicated method for calculating these by-pass condensers, but this method is quite rapid and gives conservative values. The loss due to incomplete by-passing will be less than 1% except for the cathode by-pass where it will be about 3%. The size condenser may be halved where economy is essential unless stages are cascaded and highest quality is required.

